

## **ELECTRIC STRESS DUE TO H.V**

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## INTRODUCTION

• The electric field in the insulation material must be known under all possible conditions of operation, so that the insulation can be designed and chosen to have a dielectric strength greater than the applied field levels.

## INTRODUCTION

- In high voltage engineering we are particularly interested in electric and magnetic fields.
- Electric fields are caused by the voltage difference between electrodes while magnetic fields are caused by currents flowing in conductors.
- The performance of electric insulating materials is adversely affected by excessive electric field magnitudes.

## INTRODUCTION

- High AC currents cause time-varying magnetic fields that induce voltages in conducting loops.
- Similarly, high time-varying currents due to lightning may cause induced voltages. These overvoltages cause high electric fields in power system components that may cause failure of the insulation systems.

- The work done on a charge when moved is E, is the electric potential. where dl is the path that the charge is moved, or
- Gauss theorem: for closed surface S

$$\iint \overline{E} \cdot d\overline{S} = \frac{q}{\varepsilon_0}$$

$$\nabla \cdot \vec{D} = \rho$$

#### (Poisson's equation)

• The potential at a point plays an important role in obtaining any information regarding the electrostatic field at that point. The electric field intensity can be obtained from the potential by gradient operation on the potential

$$E = -\nabla V$$
 (1.1)  
The electric flux density  
$$D = \varepsilon E$$
 (1.2)

• The divergence of this flux density which is again a differentiation results in volume charge density.

$$\nabla \cdot D = \rho_v$$

(1.3)

• Writing  $\varepsilon E = D$  in equation (1.3) we have

 $\nabla \cdot \varepsilon E = \rho_{v}$  $-\nabla \cdot \varepsilon \cdot \nabla V = \rho_{v}$  $\varepsilon \nabla^{2} V = -\rho_{v}$  $\nabla^{2} V = -\frac{\rho_{v}}{\varepsilon}$ 

(1.4)

• This is known as Poisson's equation. However, in most of the high voltage equipments, space charges are not present and hence  $\rho_v = 0$  and hence equation (1.4) is written as

 $\nabla^2 V = 0$ 

• is known as Laplace's equation

• Here  $\nabla$  is a vector operator and is termed as del operator and expressed mathematically in Cartesian coordinates as (1.5)

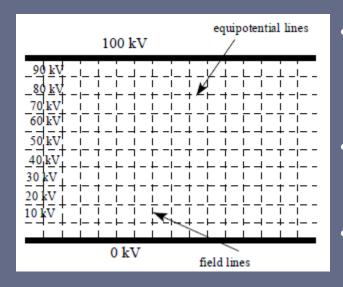
$$\nabla = \frac{\partial}{\partial x} \,\overline{a}_x + \frac{\partial}{\partial y} \,\overline{a}_y + \frac{\partial}{\partial z} \,\overline{a}_z$$

• where  $a_x$ ,  $a_y$  and  $a_z$  are unit vectors in the respective increasing directions.

• Hence Laplace's equation in Cartesian coordinates is given as

$$\nabla^2 V = \frac{\partial^2 V}{\partial x^2} + \frac{\partial^2 V}{\partial y^2} + \frac{\partial^2 V}{\partial z^2} = 0$$

• Uniform fields: If a voltage difference exist between two parallel plate electrodes of large dimensions, the electrostatic field between the plates is uniform.



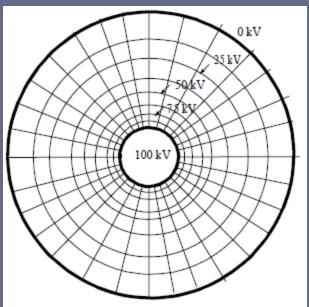
- Note that the equipotential lines are equidistant and that the field strength E is constant throughout the region. The field is therefore a uniform field.
- The lines perpendicular to the equipotential lines are known as field lines.
- The field lines indicate the direction that a positive charge would move if placed in the field

#### • In general, the electric field strength is given by:

$$E = \frac{V}{d}$$

V: voltage between platesd: distance between the plates.

• Non-uniform fields: the field strength is not constant throughout the region.



Concentric cylindrical cable

V: voltage between the electrodesb: outer radiusa: inner radiusr: distance from center line

Note that the equipotential lines are much closer together near the inner conductor, resulting in higher field strength near the inner conductor. The field strength E is therefore not constant throughout the region and such a field is known as a non-uniform field.

It can be shown that the electric field strength E a distance *r* from the center line of the configuration is given by:

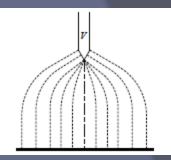
$$E_r = \frac{V}{r\ln(b/a)}$$

- In high voltage applications the dielectric strength of insulating materials are stressed by electric field.
- The electric stress to which an insulating material is subjected to is numerically equal to the voltage gradient and is equal to the electric field intensity.

$$\vec{E} = -\nabla V = -\nabla \Phi$$

- where  $\Phi$  is the applied voltage and  $\nabla$  is the gradient.
- The dielectric strength of an insulating material can be defined as the maximum dielectric stress which the material can withstand.

• The field efficiency factor  $\eta$  is defined as •  $\eta = \frac{E_{av}}{E_{max}}$ 



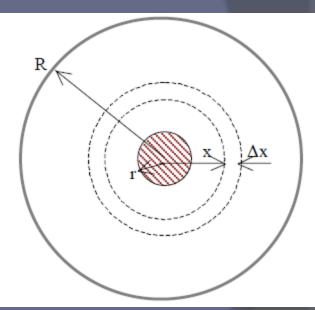
- $E_{av}$  is the average value of electric field  $E_{max}$  is the maximum value of the field. This value indicates how much the level of non-uniformity of the field is.
- The average value of the field strength of an air gap is defined by equation:
- $E_{av} = \frac{V}{d}$
- V is applied voltage and d is the thickness of the insulation between the electrodes.

Consider a single core cable with the following data. r = radius of core(m)

- *R* = radius of earthed sheath (*m*)
- q = charge/unit length of cable (C/m)
- $D = electric flux density (C/m^2)$

 $\varepsilon_0$  = permittivity of free space

 $= 1/(4\pi \times 9 \times 10^{9}) \text{ F/m}$ 

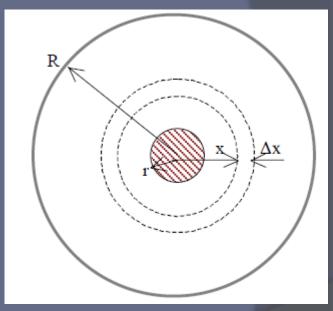


- Consider a single core cable (figure 5.9) with the following data.
- r = radius of core (m)
- *R* = radius of earthed sheath (*m*)
- Q = charge(C)
- $D = electric flux density (C/m^2)$
- $\varepsilon_0$  = permittivity of free space

 $= 1/(4\pi \ x \ 9 \ x \ 10^9) \ F/m$ 

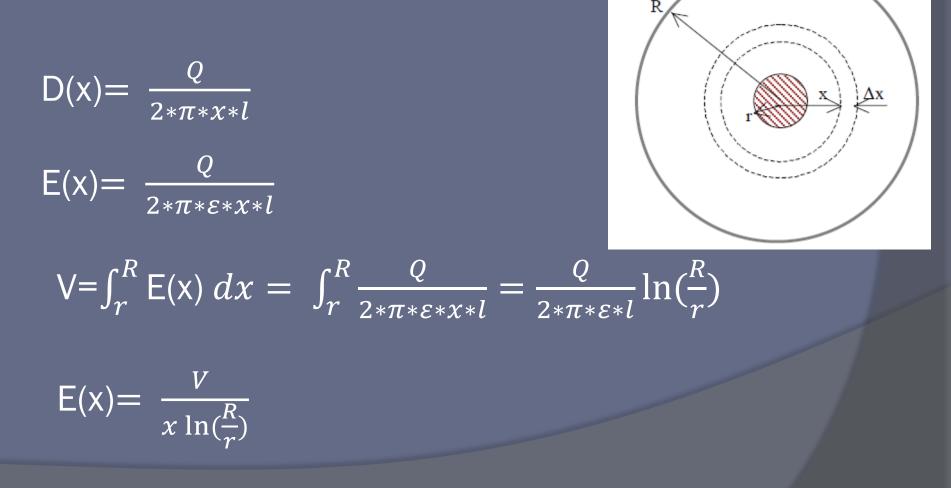
 $D(x) 2 * \pi *x*I=Q$ 

$$\mathsf{D}(\mathsf{x}) = \frac{Q}{2 \ast \pi \ast 2}$$

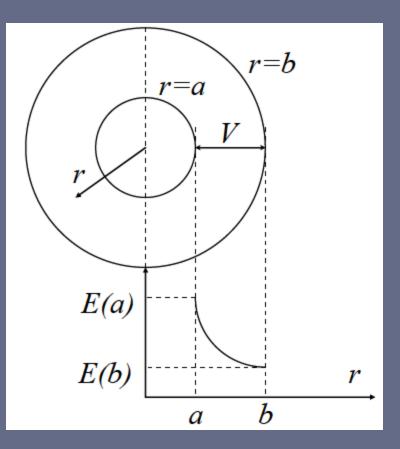


$$\oint_{S} \mathbf{D} \cdot d\mathbf{s} = Q$$

## Consider a single core cable (figure 5.9) with the following data.



#### Single core cable



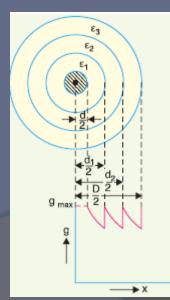
Highest stress occurs at surface of inner conductor. In HV cables, this is taken as the *operating stress*, which is the determining factor in the design. The field factor is very low, indicating the dielectric material is not effectively utilized.

The process of achieving uniform electrostatic stress in the dielectric of cables is known as grading of cables.

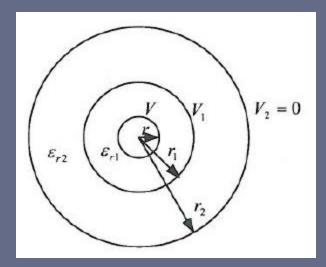
 Capacitance Grading: The process of achieving uniformity in the dielectric stress by using layers of different dielectrics is known as capacitance grading.

$$\frac{1}{\varepsilon_1 d} = \frac{1}{\varepsilon_2 d_1} = \frac{1^{\dagger}}{\varepsilon_3 d_2}$$
$$\varepsilon_1 d = \varepsilon_2 d_1 = \varepsilon_3 d_2$$

$$V = \frac{g_{1max}}{2} d \log_e \frac{d_1}{d} + \frac{g_{2max}}{2} d_1 \log_e \frac{d_2}{d_1} + \frac{g_{3max}}{2} d_2 \log_e \frac{D}{d_2}$$

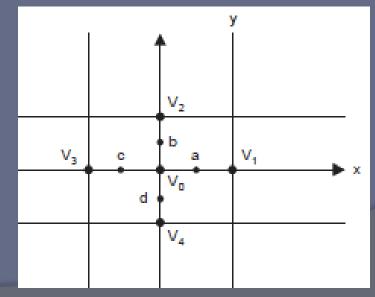


Exercise: A single core, lead covered capacitance graded cable is to be designed for 60 kV peak voltage to ground. The conductor radius is 15 mm and there are two concentric layers of insulation materials with relative permittivities of 5 and 3 respectively and maximum permissible electric stress is 4 and 3 kV/mm (Peak), respectively. Calculate the minimum inner radius ( $r_1$  and  $r_2$ ) for the two mediums.



- Analytical solutions exist only for simple geometries and linear material behavior.
- For complex geometry, one has to use the numerical methods to solve field problems.

Let us assume that voltage variations is a two dimensional problem i.e. it varies in x-y plane and it does not vary along z-coordinate and let us divide the interior of a cross section of the region where the potential distribution is required into squares of length h on a side as shown in Fig.



Assuming the region to be charge free

$$\nabla \cdot D = 0$$
 or  $\nabla \cdot E = 0$ 

• and for a two-dimensional situation

$$\frac{\partial E_x}{\partial x} + \frac{\partial E_y}{\partial y} = 0$$

• From Lap. Eq (1).

$$\frac{\partial^2 V}{\partial x^2} + \frac{\partial^2 V}{\partial y^2} = 0$$

Approximate values for these partial derivatives may be obtained in terms of the assumed values (Here  $V_0$  is to be obtained when  $V_1$ ,  $V_2$ ,  $V_3$  and  $V_4$  are known in Fig. 1.

$$\frac{\partial V}{\partial x}\Big|_{a} = \frac{V_{1} - V_{0}}{h} \quad \text{and} \quad \frac{\partial V}{\partial x}\Big|_{c} = \frac{V_{0} - V_{3}}{h}$$
From the gradients
$$\frac{\partial^{2} V}{\partial x^{2}}\Big|_{0} = \frac{\frac{\partial V}{\partial x}\Big|_{a} - \frac{\partial V}{\partial x}\Big|_{c}}{h} = \frac{V_{1} - V_{0} - V_{0} + V_{3}}{h^{2}}$$
Similarly
$$\frac{\partial^{2} V}{\partial y^{2}}\Big|_{0} = \frac{V_{2} - V_{0} - V_{0} + V_{4}}{h^{2}}$$

Substituting in equation (1) we have

$$\frac{\partial^2 V}{\partial x^2} + \frac{\partial^2 V}{\partial y^2} = \frac{V_1 + V_2 + V_3 + V_4 - 4V_0}{h^2} = 0$$
$$V_0 = \frac{1}{4} (V_1 + V_2 + V_3 + V_4)$$

As mentioned earlier the potentials at four corners of the square are, these correspond to boundary potentials which are known a priori. The process is repeated over the entire region until the difference in values is less than a pre-specified value.

**Example: The Poisson's equation** 

 $\frac{\partial^2 V}{\partial x^2} + V = 0$ 

• Over a one-dim. Region with  $0 \le x \le 1$  and boundary conditions V(0)=0 and V(1)=1 is to be solved.

- The region is divided into n equal segments (elements), with (n+1) grid points. Let us assume n=4
- The grid points are denoted by i=0, 1, 2, 3...
- At the grid points x=i\*h, where h is the spacing between two adjacent grid points.

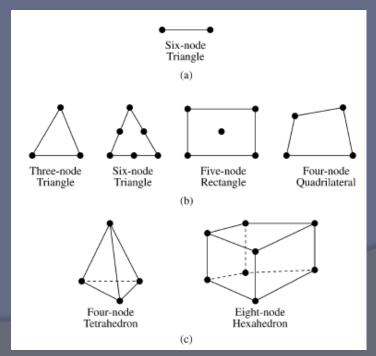
Example:

- We can approximate the differential equation with central-difference formula
- $\frac{\partial}{\partial x} \frac{\partial V}{\partial x} = \frac{\partial}{\partial x} \left[ \frac{V_{i+1} V_i}{h} \right] = \frac{1}{h} \left\{ \left[ \frac{V_{i+1} V_i}{h} \right] \left[ \frac{V_i V_i}{h} \right] \right\}$
- $=\frac{1}{h^2} \left[ V_{i+1} 2 * V_i + V_{i-1} \right]$
- $16[V_{i_{+}1} 2 * V_i + V_{i_{-}1}] + V_i = 0$
- From this the system of equation is established for i=1, 2,3 with h=1/4
- A matrix of 3X 3 is formulated to solve the three unknowns.

- The finite element analysis of any problem involves basically four steps:
- discretizing the solution region into a finite number of sub-regions or elements,
- deriving governing equations for a typical element,
- assembling of all elements in the solution region, and
- solving the system of equations obtained.

- The finite element analysis of any problem involves basically four steps:
- discretizing the solution region into a finite number of sub-regions or elements,
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Discretization of the continuum involves dividing up the solution region into subdomains, called finite elements. The Figure, shows some typical elements for one-,two-, and three-dimensional problems.

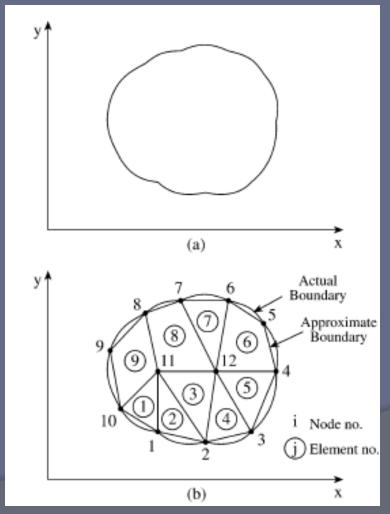


• As an application of FEM to electrostatic problems, let us apply the four steps mentioned above to solve Laplace's equation, $\nabla^2 V = 0$ 

#### **Finite Element Discretization**

• To find the potential distribution V (x, y) for the twodimensional solution region shown in Fig, we divide the region into a number of finite elements as illustrated in Fig. 6.2(b). In Fig. 6.2(b), the solution region is subdivided into nine nonoverlapping finite elements 6, 8, and 9 are four-node quadrilaterals, while other elements are three-node triangles. In practical situations.

#### **Finite Element Discretization**



#### **Finite Element Discretization**

We seek an approximation for the potential V<sub>e</sub> within an element e and then interrelate the potential distribution in various elements such that the potential is continuous across interelement boundaries. The approximate solution for the whole region is

$$V(x, y) \simeq \sum_{e=1}^{N} V_e(x, y),$$

where N is the number of elements into which the solution region is divided.

#### Finite Element Discretization

 The most common form of approximation for V<sub>e</sub> within an element is polynomial approximation, namely,

$$V_e(x, y) = a + bx + cy \quad (1)$$

for a triangular element and for a quadrilateral element.

$$V_e(x, y) = a + bx + cy + dxy$$

#### **Finite Element Discretization**

 We use triangular elements throughout our analysis in this chapter. Notice that our assumption of linear variation of potential within the triangular element as in Eq. is the same as assuming that the electric field is uniform within the element, i.e.

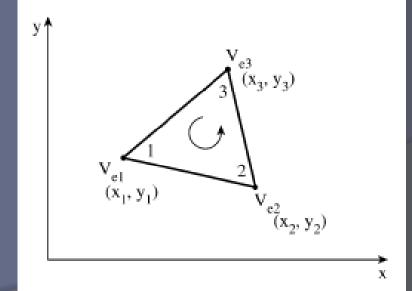
$$\mathbf{E}_e = -\nabla V_e = -\left(b\mathbf{a}_x + c\mathbf{a}_y\right)$$

#### **Element Governing Equations**

Consider a typical triangular element shown in Fig. The potential  $V_{e1}$ ,  $V_{e2}$ , and  $V_{e3}$  at nodes 1, 2, and 3, respectively, are obtained using Eq. (\*), i.e.,

$$\begin{bmatrix} V_{e1} \\ V_{e2} \\ V_{e3} \end{bmatrix} = \begin{bmatrix} 1 & x_1 & y_1 \\ 1 & x_2 & y_2 \\ 1 & x_3 & y_3 \end{bmatrix} \begin{bmatrix} a \\ b \\ c \end{bmatrix}$$

\*\*



#### **Element Governing Equations**

# The coefficients *a*, *b* and *c* are determined from Eq. (\*\*) as

$$\begin{bmatrix} a \\ b \\ c \end{bmatrix} = \begin{bmatrix} 1 & x_1 & y_1 \\ 1 & x_2 & y_2 \\ 1 & x_3 & y_3 \end{bmatrix}^{-1} \begin{bmatrix} V_{e1} \\ V_{e2} \\ V_{e3} \end{bmatrix}$$

# Element Governing Equations Substituting this into Eq. (\*) gives

$$V_{e} = \begin{bmatrix} 1 \ x \ y \end{bmatrix} \frac{1}{2A} \begin{bmatrix} (x_{2}y_{3} - x_{3}y_{2}) & (x_{3}y_{1} - x_{1}y_{3}) & (x_{1}y_{2} - x_{2}y_{1}) \\ (y_{2} - y_{3}) & (y_{3} - y_{1}) & (y_{1} - y_{2}) \\ (x_{3} - x_{2}) & (x_{1} - x_{3}) & (x_{2} - x_{1}) \end{bmatrix} \begin{bmatrix} V_{e1} \\ V_{e2} \\ V_{e3} \end{bmatrix}$$

Or

 $V_{e} = \sum_{i=1}^{3} \alpha_{i}(x, y) V_{ei}$ 

Note that Eq. gives the potential at any point (x, y) within the element provided that the potentials at the vertices are known. This is unlike finite difference analysis, where the potential is known at the grid points only.

(3)

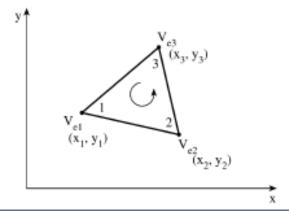
### **Element Governing Equations**

Where  $\alpha_1 = \frac{1}{24} \left[ (x_2 y_3 - x_3 y_2) + (y_2 - y_3) x + (x_3 - x_2) y \right],$  $\alpha_2 = \frac{1}{2A} \left[ (x_3 y_1 - x_1 y_3) + (y_3 - y_1) x + (x_1 - x_3) y \right],$  $\alpha_3 = \frac{1}{2A} \left[ (x_1 y_2 - x_2 y_1) + (y_1 - y_2) x + (x_2 - x_1) y \right],$  $1 x_1 y_1$  $2A = \begin{vmatrix} 1 & x_2 & y_2 \end{vmatrix}$  $1 x_3 y_3$ where  $= (x_1y_2 - x_2y_1) + (x_3y_1 - x_1y_3) + (x_2y_3 - x_3y_2)$  $A = \frac{1}{2} \left[ (x_2 - x_1) (y_3 - y_1) - (x_3 - x_1) (y_2 - y_1) \right]$ 

A is the area of the element

### **Element Governing Equations**

The value of A is positive if the nodes are numbered counterclockwise (starting from any node) as shown by the arrow in Fig



Typical triangular element; local node numbering 1-2-3 must proceed counterclockwise as indicated by the arrow.

Element Governing Equations Note that Eq. gives the potential

$$V_e = \sum_{i=1}^3 \alpha_i(x, y) V_{ei}$$

- at any point (x, y) within the element provided that the potentials at the vertices are known.
- Also note that α<sub>i</sub> are linear interpolation functions. They are called the *element shape functions* and they have the following properties:

$$\alpha_i = \begin{cases} 1, & i = j \\ 0, & i \neq j \end{cases}$$
$$\sum_{i=1}^3 \alpha_i(x, y) = 1$$

# **Element Governing Equations**

The functional corresponding to Laplace's equation  $\nabla^2 V = 0$  is given by

$$W_{\epsilon} = \frac{1}{2} \int \epsilon |\mathbf{E}_{\epsilon}|^2 dS = \frac{1}{2} \int \epsilon |\nabla V_{\epsilon}|^2 dS$$
<sup>(4)</sup>

• (Physically, the functional  $W_e$  is the energy per unit length associated with the element e.)

Element Governing Equations From Eq. (4),

$$\nabla V_e = \sum_{i=1}^3 V_{ei} \nabla \alpha_i$$

Substituting Eq. (3) into (4) gives

$$W_{e} = \frac{1}{2} \sum_{i=1}^{3} \sum_{j=1}^{3} \epsilon V_{ei} \left[ \int \nabla \alpha_{i} \cdot \nabla \alpha_{j} \, dS \right] V_{ej}$$

If we define the term in brackets as

$$C_{ij}^{(e)} = \int \nabla \alpha_i \cdot \nabla \alpha_j \, dS \,,$$

**Element Governing Equations** we may write the Eq. in matrix form as

$$W_e = \frac{1}{2} \epsilon [V_e]^t [C^{(e)}] [V_e]$$

where the superscript *t* denotes the transpose of the matrix,

$$\begin{bmatrix} V_e \end{bmatrix} = \begin{bmatrix} V_{e1} \\ V_{e2} \\ V_{e3} \end{bmatrix}$$
$$\begin{bmatrix} C^{(e)} \end{bmatrix} = \begin{bmatrix} C_{11}^{(e)} & C_{12}^{(e)} & C_{13}^{(e)} \\ C_{21}^{(e)} & C_{22}^{(e)} & C_{23}^{(e)} \\ C_{31}^{(e)} & C_{32}^{(e)} & C_{33}^{(e)} \end{bmatrix}$$

### **Element Governing Equations**

The matrix [C(e)] is usually called the element coefficient matrix (or "stiffness matrix"). The element  $C(e)_{ij}$  of the coefficient matrix may be regarded as the coupling between nodes i and j. For example

$$C_{12}^{(e)} = \int \nabla \alpha_1 \cdot \nabla \alpha_2 \, dS$$
  
=  $\frac{1}{4A^2} [(y_2 - y_3) (y_3 - y_1) + (x_3 - x_2) (x_1 - x_3)] \int dS$   
=  $\frac{1}{4A} [(y_2 - y_3) (y_3 - y_1) + (x_3 - x_2) (x_1 - x_3)]$ 

# **Element Governing Equations**

Similarly

$$C_{13}^{(e)} = \frac{1}{4A} [(y_2 - y_3) (y_1 - y_2) + (x_3 - x_2) (x_2 - x_1)],$$
  

$$C_{23}^{(e)} = \frac{1}{4A} [(y_3 - y_1) (y_1 - y_2) + (x_1 - x_3) (x_2 - x_1)],$$
  

$$C_{11}^{(e)} = \frac{1}{4A} [(y_2 - y_3)^2 + (x_3 - x_2)^2],$$
  

$$C_{22}^{(e)} = \frac{1}{4A} [(y_3 - y_1)^2 + (x_1 - x_3)^2],$$
  

$$C_{33}^{(e)} = \frac{1}{4A} [(y_1 - y_2)^2 + (x_2 - x_1)^2]$$
  

$$C_{21}^{(e)} = C_{12}^{(e)}, \quad C_{31}^{(e)} = C_{13}^{(e)}, \quad C_{32}^{(e)} = C_{23}^{(e)}$$

### **Assembling of All Elements**

Having considered a typical element, the next step is to assemble all such elements in the solution region. The energy associated with the assemblage of elements is

$$W = \sum_{e=1}^{N} W_e = \frac{1}{2} \epsilon [V]^t [C] [V]$$

$$\begin{bmatrix} V_1 \\ V_2 \\ V_3 \\ \vdots \\ V_n \end{bmatrix},$$

*n* is the number of nodes, *N* is the number of elements, and [*C*] is called the overall or *global coefficient matrix,* which is the assemblage of individual element coefficient matrices.

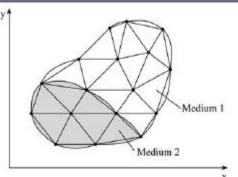
# **Assembling of All Elements**

 Notice that we have assumed that the whole solution region is homogeneous so that ε is constant. For an inhomogeneous solution region the region is discretized such that each finite element is homogeneous.

• For we may replace multiply the integrand in Eq.

by  $\varepsilon_r$  .

$$C_{ij}^{(e)} = \int \nabla \alpha_i \cdot \nabla \alpha_j \, dS \,,$$

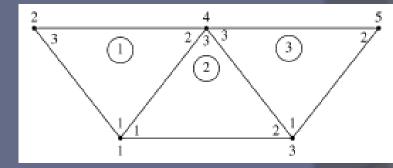


# **Assembling of All Elements**

Assembly of three elements; i-j-k corresponds to local numbering (1-2-3) of the element

The numbering of nodes 1, 2, 3, 4, and 5 is called *global* numbering. The numbering *i-j -k* is called *local* numbering, and it corresponds with 1 - 2 - 3 of the element

Note that the local numbering must be in counterclockwise sequence starting from any node of the element.



For example, for element 3, the global numbering 3 - 5 - 4 corresponds with local numbering 1 - 2 - 3 of the element.

# **Assembling of All Elements**

The global coefficient matrix is expected to have the form which is a 5 × 5 matrix since five nodes (n = 5) are involved.

$$[C] = \begin{bmatrix} C_{11} & C_{12} & C_{13} & C_{14} & C_{15} \\ C_{21} & C_{22} & C_{23} & C_{24} & C_{25} \\ C_{31} & C_{32} & C_{33} & C_{34} & C_{35} \\ C_{41} & C_{42} & C_{43} & C_{44} & C_{45} \\ C_{51} & C_{52} & C_{53} & C_{54} & C_{55} \end{bmatrix}$$

# **Assembling of All Elements**

- Again, C<sub>ij</sub> is the coupling between nodes i and j. We obtain C<sub>ij</sub> by using the fact that the potential distribution must be continuous across inter-element boundaries.
- The contribution to the *i*, *j* position in [C] comes from all elements containing nodes *i* and *j*. For example, in the Fig., elements 1 and 2 have node 1 in common; hence

$$C_{11} = C_{11}^{(1)} + C_{11}^{(2)}$$

• Node 2 belongs to element 1 only; hence  $C_{22} = C_{33}^{(1)}$ 

### **Assembling of All Elements**

• Node 4 belongs to elements 1, 2, and 3; consequently  $C_{44} = C_{22}^{(1)} + C_{33}^{(2)} + C_{33}^{(3)}$ 

• Nodes 1 and 4 belong simultaneously to elements 1 and 2; hence  $C_{14} = C_{41} = C_{12}^{(1)} + C_{13}^{(2)}$ 

• Since there is no coupling (or direct link) between nodes 2 and 3,  $C_{23} = C_{32} = 0$ 

# **Assembling of All Elements**

 Continuing in this manner, we obtain all the terms in the global coefficient matrix by inspection of the Fig.

as

$$\begin{bmatrix} C_{11}^{(1)} + C_{11}^{(2)} & C_{13}^{(1)} & C_{12}^{(2)} & C_{12}^{(1)} + C_{13}^{(2)} & 0 \\ C_{31}^{(1)} & C_{33}^{(1)} & 0 & C_{32}^{(1)} & 0 \\ C_{21}^{(2)} & 0 & C_{22}^{(2)} + C_{11}^{(3)} & C_{23}^{(2)} + C_{13}^{(3)} & C_{12}^{(3)} \\ C_{21}^{(1)} + C_{31}^{(2)} & C_{23}^{(1)} & C_{32}^{(2)} + C_{31}^{(3)} & C_{22}^{(1)} + C_{33}^{(2)} + C_{33}^{(3)} & C_{32}^{(3)} \\ 0 & 0 & C_{21}^{(3)} & C_{23}^{(3)} & C_{23}^{(2)} \end{bmatrix}$$

# **Assembling of All Elements**

- Note the following properties of the matrix [C]:
- It is symmetric ( $C_{ij} = C_{ji}$ ) just as the element coefficient matrix.
- Since C<sub>ij</sub> = 0 if no coupling exists between nodes i and j, it is expected that for a large number of elements [C] becomes sparse.
   It is singular.

# **Solving the Resulting Equations**

It can be shown that Laplace's equation is satisfied when the total energy in the solution region is minimum. Thus we require that the partial derivatives of W with respect to each nodal value of the potential be zero, i.e.,

$$\frac{\partial W}{\partial V_1} = \frac{\partial W}{\partial V_2} = \dots = \frac{\partial W}{\partial V_n} = 0$$
$$\frac{\partial W}{\partial V_k} = 0, \qquad k = 1, 2, \dots, n$$

### Solving the Resulting Equations

For example, to get  $\partial W/\partial V1 = 0$  for the finite element mesh of the Fig., we substitute the coefficient matrix

into Eq. 
$$w = \sum_{e=1}^{N} w_e = \frac{1}{2} \epsilon [v]'[c][v]$$
 and take the partial derivative

of W with respect to  $V_1$ . We obtain

$$0 = \frac{\partial W}{\partial V_1} = 2V_1C_{11} + V_2C_{12} + V_3C_{13} + V_4C_{14} + V_5C_{15} + V_2C_{21} + V_3C_{31} + V_4C_{41} + V_5C_{51}$$

 $0 = V_1 C_{11} + V_2 C_{12} + V_3 C_{13} + V_4 C_{14} + V_5 C_{15}$ 

Solving the Resulting Equations In general,  $\partial W / \partial V_k = 0$  leads to

$$0 = \sum_{i=1}^{n} V_i C_{ik}$$

• where *n* is the number of nodes in the mesh. By writing the Eq. for all nodes k = 1, 2, ..., n, we obtain a set of simultaneous equations from which the solution of  $[V]^t = [V_1, V_2, ..., V_n]$  can be found.

# **Solving the Resulting Equations**

Iteration Method: Suppose node 1 in the Fig., for example, is a free node

$$V_1 = -\frac{1}{C_{11}} \sum_{i=2}^5 V_i C_{1i}$$

Thus, in general, at node k in a mesh with n nodes

$$V_k = -\frac{1}{C_{kk}} \sum_{i=1, i \neq k}^n V_i C_{ki}$$